

ERASynth: An Open Source, Arduino-Compatible RF Signal Generator with Wi-Fi Connectivity

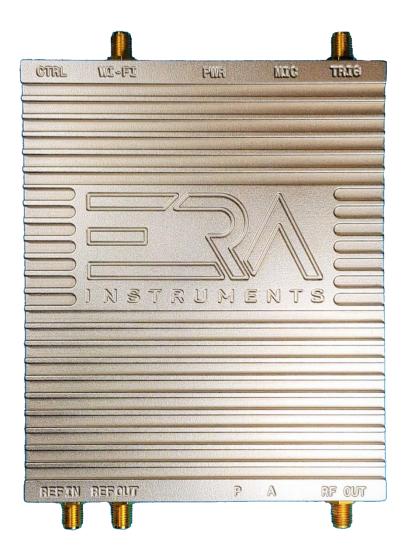
DATASHEET





GENERAL DESCRIPTION

ERASynth is an open source analog RF signal generator featuring an Arduino Due microcontroller and an ESP8266 powered web GUI. ERASynth uses advanced PLL/VCO technology, coupled with an internal ultra-low phase noise frequency reference to form a programmable analog signal generator capable of generating a low phase noise signals up to 20 GHz. ERASynth provides fast frequency switching and fine tuning resolution using a multi-loop PLL architecture. ERASynth also offers frequency, amplitude and pulse modulation capabilities. The frequency tuning and control commands are loaded into the instrument via the serial interface or via the web GUI or Windows GUI.





FEATURES

Architecture: Multiloop Integer-N PLL driven by a tunable reference.

Frequency Range:

ERASynth: 250 kHz to 6 GHz
ERASynth+: 250 kHz to 15 GHz
ERASynth++: 250 kHz to 20 GHz

Amplitude Range: -60 to +15 dBm (typical)

Phase Noise: -120 dBc/Hz (typical phase noise @ 1 GHz output and 10 kHz offset)

Frequency Switching Time: 250 µs (typical)

Reference: Ultra-low noise 100 MHz VCXO locked to a

• ±0.5 ppm 10 MHz TCXO for ERASynth

• ±25 ppb 10 MHz OCXO for ERASynth+ and ERASynth++

• 10 MHz external reference

MCU: Arduino Due board with BGA package Atmel Microcontroller (ATSAM3X8EA-CU)

Interfaces:

- Wi-Fi interface for web-based GUI access
- Serial-USB (mini USB) for serial access
- Micro USB for power input
- Trigger Input (SMA) for triggered sweep
- REF In (SMA) for external reference input
- REF Out (SMA) for 10 MHz reference output
- RF Out

Dimensions: 10 cm x 14.5 cm x 2 cm

Weight: 400 g (14.1 oz)

Power Input: 5 to 12 V

Power Consumption:

• Typ < 6 W for ERASynth

Typ < 7 W for ERASynth+ and ERASynth++

Enclosure: Precision-milled, nickel-plated aluminum case

Open Source: Schematics, embedded Arduino code, Web GUI source code, and RS-232

command set

Modulation: FM, AM, Pulse (Internal and external)



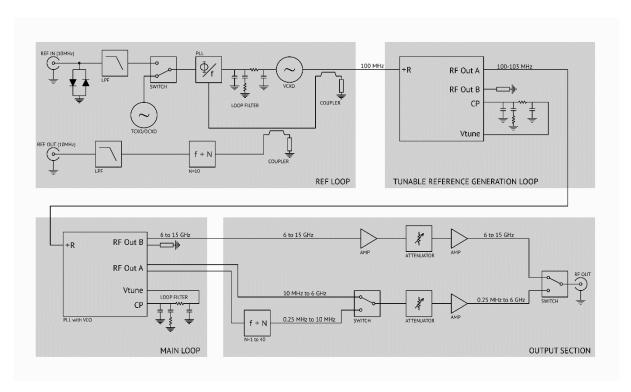


Figure 1: ERASynth general block diagram

ORDER GUIDE

| | ERASynth | ERASynth+ | ERASynth++ |
|---|------------------------------|-----------------------------------|-----------------------------------|
| Frequency Range | 250 kHz to 6 GHz | 250 kHz to 15 GHz | 250 kHz to 20 GHz (*) |
| Architecture | LMX2594 driven by LMX2594 | LMX2594 driven by LMX2594 | LMX2595 driven by LMX2594 |
| Reference | ±0.5 ppm TCXO | ±0.5 ppm TCXO and ±25 ppb OCXO | ±0.5 ppm TCXO and ±25 ppb OCXO |
| Price | \$749 | \$1249 | \$1749 |
| * ERASynth++ comes with an external 15 to 20 GHz cavity filter for subharmonic rejection. | | | |



ELECTRICAL CHARACTERISTICS

| | Minimum | Typical | Maximum |
|---|---------|-----------------|------------|
| Supply Voltage | 4.5 V | 5 V | 12 V |
| Supply Current | | 1.1 A | |
| Supply Current, RF Out Muted | | 300 mA | |
| Amplitude Accuracy | | ± 1.5 dB | |
| External Reference Input Level | -10 dBm | 0 dBm | +10 dBm |
| External Reference Locking Range | | 10 MHz ± 30 ppm | |
| External Trigger Low Level Input Voltage | 0 V | | 0.7 V |
| External Trigger High Level Input Voltage | 2 V | | 3.3 V |
| External Modulation Input Voltage Level | | | 0 ± 1.65 V |
| RF Output Impedance | | 50 Ohm | |

THERMAL CHARACTERISTICS

Operating temperature range: 0 to +50 °C

Non-operating temperature range: -40 to +85 °C

Warm-up time: 10 minutes



TYPICAL PERFORMANCE

1) Max Unleveled Output Power

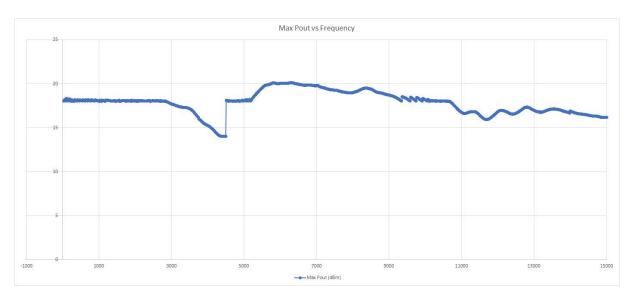


Figure 2: ERASynth+ Max Unleveled Power Output

2) Spectral Purity

ERASynth's multiloop architecture minimizes the spurious artifacts commonly encountered in fractional frequency synthesizers.

Broadband Non-Harmonic Spurious Emissions

| Frequency | dBc (typical) at 0 dBm specified output power | |
|--------------------|---|--|
| 250 kHz-30 MHz | -67 dBc | |
| 30 MHz-4500 MHz | -63 dBc | |
| 4500 MHz-20000 MHz | -58 dBc | |



Harmonics (2nd or 3rd harmonics, whichever is worse)

| Frequency | dBc (typical) at 0 dBm specified output power |
|-----------|---|
| 1 MHz | -29 dBc |
| 3 MHz | -35 dBc |
| 10 MHz | -47 dBc |
| 20 MHz | -47 dBc |
| 30 MHz | -55 dBc |
| 100 MHz | -10 dBc |
| 300 MHz | -10 dBc |
| 1 GHz | -14 dBc |
| 2 GHz | -16 dBc |
| 3 GHz | -25 dBc |
| 6 GHz | -22 dBc |
| 10 GHz | -33 dBc |



Sub-Harmonics (1/2 or 1/3 harmonics, whichever is worse)

| dBc (typical) at 0 dBm specified output power |
|---|
| -77 dBc |
| -77 dBc |
| -72 dBc |
| <-90 dBc |
| <-90 dBc |
| -86 dBc |
| <-90 dBc |
| -55 dBc |
| -52 dBc |
| -30 dBc |
| <-100 dBc (*) |
| |



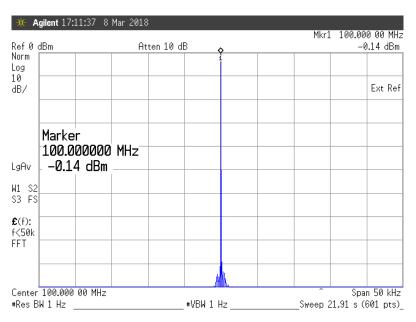


Figure 3: ERASynth+ Narrow-band Spurious Performance at 100 MHz

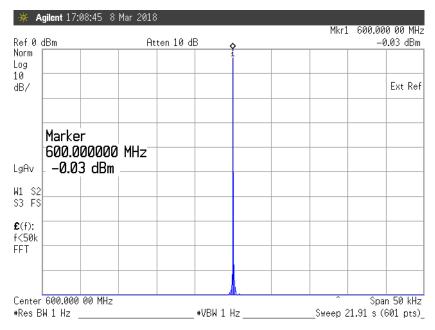


Figure 4: ERASynth+ Narrow-band Spurious Performance at 600 MHz



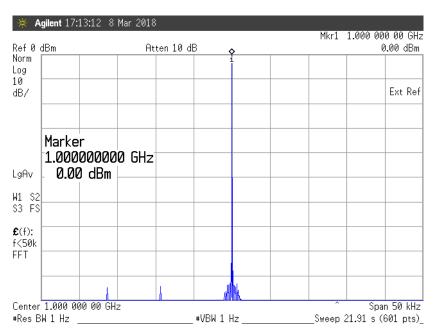


Figure 5: ERASynth+ Narrow-band Spurious Performance at 1 GHz

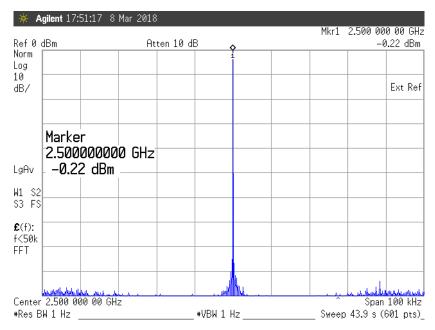


Figure 6: ERASynth+ Narrow-band Spurious Performance at 2.5 GHz



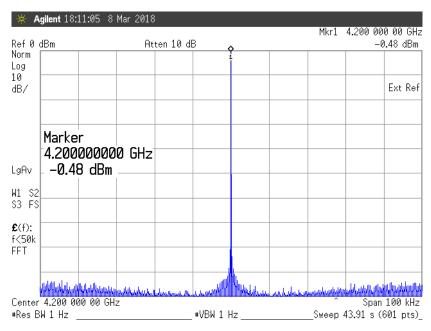


Figure 7: ERASynth+ Narrow-band Spurious Performance at 4.2 GHz

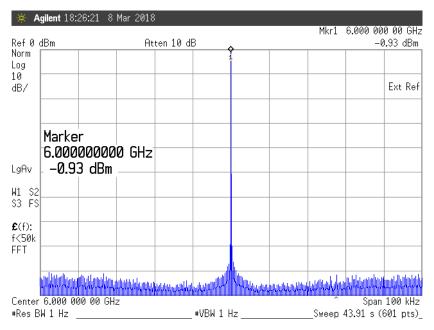


Figure 8: ERASynth+ Narrow-band Spurious Performance at 6 GHz



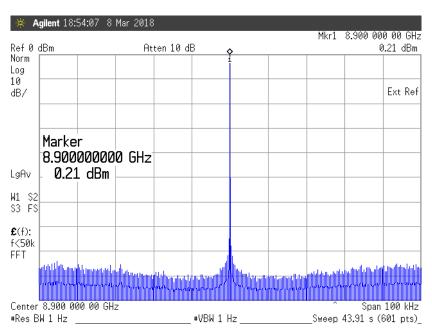


Figure 9: ERASynth+ Narrow-band Spurious Performance at 8.9 GHz

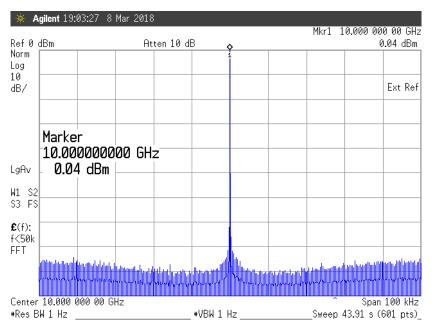


Figure 10: ERASynth+ Narrow-band Spurious Performance at 10 GHz



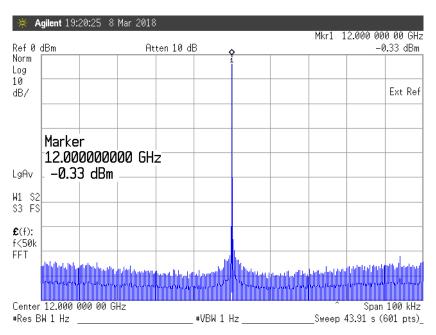


Figure 11: ERASynth+ Narrow-band Spurious Performance at 12 GHz

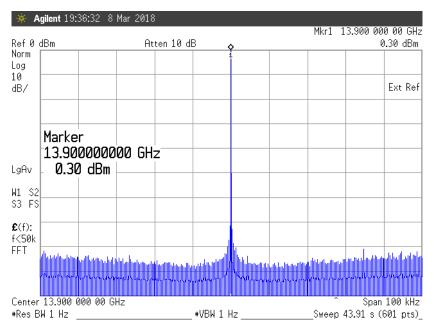


Figure 12: ERASynth+ Narrow-band Spurious Performance at 13.9 GHz



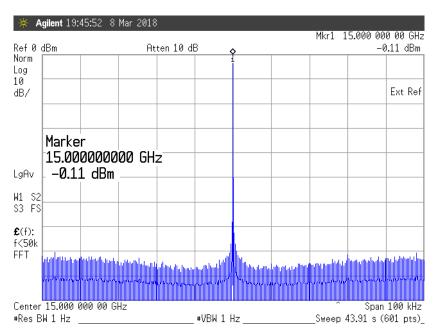


Figure 13: ERASynth+ Narrow-band Spurious Performance at 15 GHz



3) Phase Noise

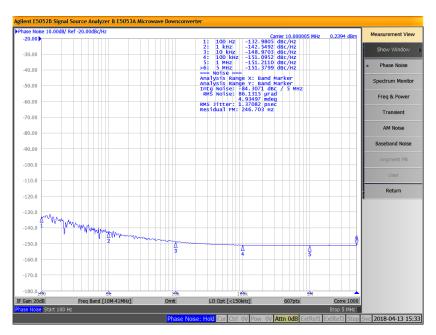


Figure 14: ERASynth+ Phase Noise Performance at 10 MHz RF Output

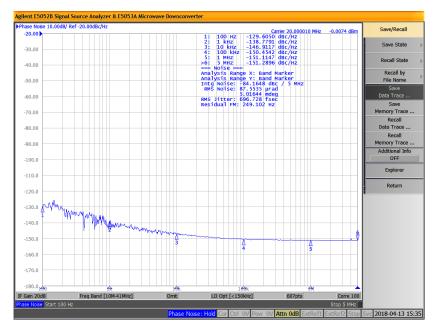


Figure 15: ERASynth+ Phase Noise Performance at 20 MHz RF Output



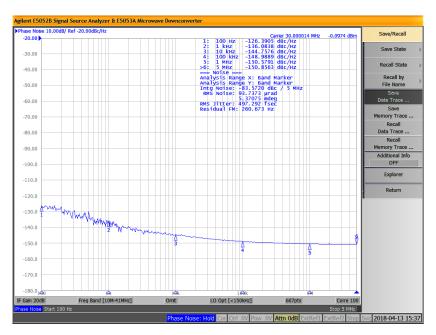


Figure 16: ERASynth+ Phase Noise Performance at 30 MHz RF Output



Figure 17: ERASynth+ Phase Noise Performance at 30.1 MHz RF Output





Figure 18: ERASynth+ Phase Noise Performance at 40 MHz RF Output



Figure 19: ERASynth+ Phase Noise Performance at 100 MHz RF Output



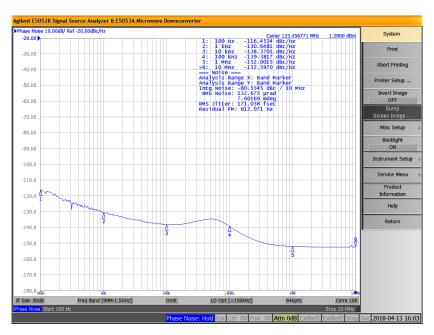


Figure 20: ERASynth+ Phase Noise Performance at 123.456789 MHz RF Output



Figure 21: ERASynth+ Phase Noise Performance at 250 MHz RF Output



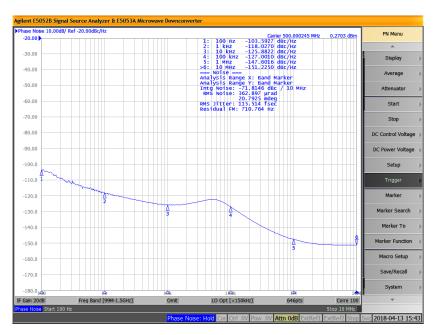


Figure 22: ERASynth+ Phase Noise Performance at 500 MHz RF Output



Figure 23: ERASynth+ Phase Noise Performance at 1 GHz RF Output



ERASynth



Figure 24: ERASynth+ Phase Noise Performance at 1.111111111 GHz RF Output



Figure 25: ERASynth+ Phase Noise Performance at 2 GHz RF Output





Figure 26: ERASynth+ Phase Noise Performance at 2.22222222 GHz RF Output



Figure 27: ERASynth+ Phase Noise Performance at 3 GHz RF Output





Figure 28: ERASynth+ Phase Noise Performance at 6 GHz RF Output



Figure 29: ERASynth+ Phase Noise Performance at 6666 MHz RF Output



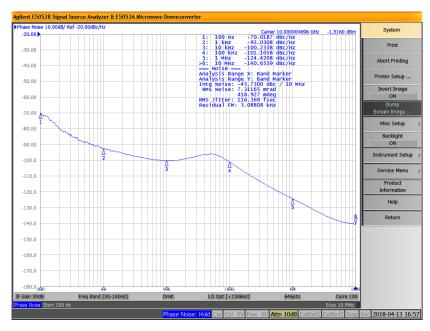


Figure 30: ERASynth+ Phase Noise Performance at 10 GHz RF Output



Figure 31: ERASynth+ Phase Noise Performance at 12 GHz RF Output



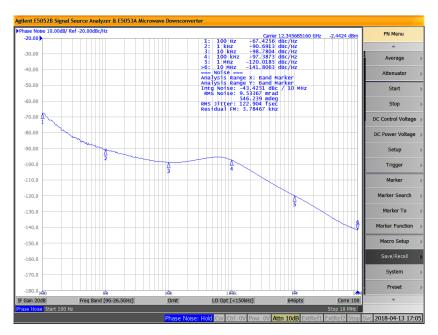


Figure 32: ERASynth+ Phase Noise Performance at 12.345678900 GHz RF Output

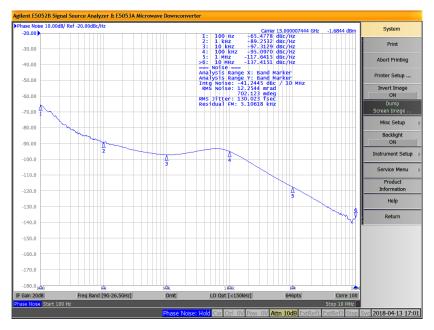


Figure 33: ERASynth+ Phase Noise Performance at 15 GHz RF Output



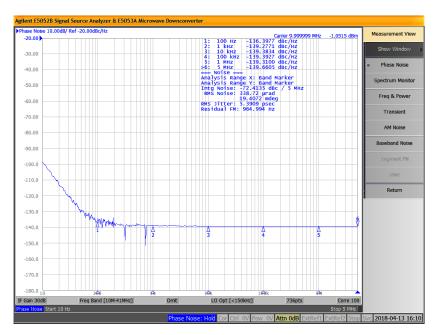


Figure 34: ERASynth+ 10 MHz REF OUT Phase Noise (Internal REF Source is selected as OCXO)



4) Modulation

Amplitude Modulation (AM)

| Modulation Depth | 30 dB (typ)* | |
|---|------------------------------|--|
| Maximum Depth (Linear) | %95 | |
| Internal Modulation Waveforms | Sine, Triangle, Ramp, Square | |
| Maximum Internal Modulation Frequency | 30 kHz (typ) | |
| Maximum External Modulation Frequency | 2 kHz (typ) | |
| External Input | ± 1.65 V (typ) | |
| External Input Impedance | 8 kΩ (typ) | |
| *Measured with power set at max. amplitude range. AM is clipped when available power (min. or max.) is reached. | | |



Narrow Band Frequency Modulation (NBFM)

| Maximum Deviation | 1 MHz | 45 Hz (typ) |
|---|--------------------------------|---------------|
| | 10 MHz | 450 Hz (typ) |
| | 100 MHz | 4500 Hz (typ) |
| | 1 GHz | 45 kHz (typ) |
| | 10 GHz | 450 kHz (typ) |
| Frequency Shift* | 27.5 °C | 5 ppm (typ) |
| | 40.0 °C | 1 ppm (typ) |
| | 43.5 °C | 400 ppb (typ) |
| | 45.3 °C | 170 ppb (typ) |
| Internal Modulation Waveforms | Sine, Triangle, Ramp, Square | |
| Maximum Internal Modulation Frequency | 30 kHz (typ) | |
| Maximum External Modulation Frequency | 20 kHz (typ) | |
| External Input | ± 1.65 V (typ) | |
| External Input Impedance | 8 kΩ (typ) | |
| Maximum External Modulation Frequency External Input | 20 kHz (typ) ± 1.65 V (typ) | |

^{*}When NBFM modulation is enabled, reference of VCXO is switched to an internal DAC. That causes a frequency shift. Temperature values are read from internal sensor



Wide Band Frequency Modulation (WBFM)

| Minimum deviation | 100 MHz | 5 kHz (typ) |
|---------------------------------------|------------------------------|---------------|
| | 1 GHz | 10 kHz (typ) |
| | 3 GHz | 30 kHz (typ) |
| | 10 GHz | 100 kHz (typ) |
| Maximum deviation | 100 MHz | 500 kHz (typ) |
| | 1 GHz | 5 MHz (typ) |
| | 3 GHz | 9.9 MHz |
| | 10 GHz | 9.9 MHz |
| Internal Modulation Waveforms | Sine, Triangle, Ramp, Square | |
| Maximum Internal Modulation Frequency | 30 kHz (typ) | |
| Maximum External Modulation Frequency | 20 kHz (typ) | |
| External Input | ± 1.65 V (typ) | |
| External Input Impedance | 8 kΩ (typ) | |



Pulse Modulation

| On/Off Ratio | 250 kHz-100 MHz | >90 dB (typ) | |
|--------------------------|-----------------|------------------------------|--|
| | 1 GHz | 88 dB (typ) | |
| | 3 GHz | 82 dB (typ) | |
| | 6 GHz | 76 dB (typ) | |
| | 10 GHz | 65 dB (typ) | |
| | 15 GHz | 75 dB (typ) | |
| Minimum Pulse Width | 300 us | 300 us (typ) | |
| Minimum Pulse Period | 650 u: | 650 us (typ) | |
| Maximum Pulse Period | 99 | 999 s | |
| Rise Time (10 to 90%) | 15 us | 15 us (typ) | |
| Fall Time (10 to 90%) | 6 us | 6 us (typ) | |
| External Input | +3.3 V = RF ON | +3.3 V = RF ON, 0 V = RF OFF | |
| External Input Impedance | 8 kΩ | 8 kΩ (typ) | |